National Semiconductor

February 1996

DS75114 Dual Differential Line Drivers

General Description

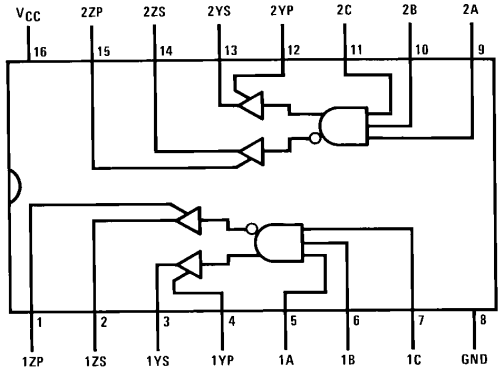
The DS75114 dual differential line driver is designed to provide differential output signals with high current capability for driving balanced lines, such as twisted pair at normal line impedances, without high power dissipation. The output stages are similar to TTL totem-pole outputs, but with the sink outputs, YS and ZS, and the corresponding active pull-up terminals, YP and ZP, available on adjacent package pins. Since the output stages provide TTL compatible output levels, these devices may also be used as TTL expanders or phase splitters.

Features

- Each circuit offers a choice of open-collector or active pull-up (totem-pole) outputs
- Single 5V supply
- Differential line operation
- Dual channels
- TTL/LS compatibility
- Designed to be interchangeable with Fairchild 9614 line drivers
- Short-circuit protection of outputs
- High current outputs
- Clamp diodes at inputs and outputs to terminate line transients
- Single-ended or differential AND/NAND outputs
- Triple inputs

Connection Diagram

Dual-In-Line Package



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Top View

Positive logic: $Y = ABC$

$Z = \overline{ABC}$

Order Number DS75114N
See NS Package Number N16A

Truth Table

Inputs			Outputs	
A	B	C	Y	Z
H	H	H	H	L
All Other Input Combinations			L	H

H = high level

L = low level

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC}	7V
Input Voltage	5.5V
OFF-State Voltage Applied to Open-Collector Outputs	12V
Maximum Power Dissipation* at 25°C	
Cavity Package	1433 mW
Molded Package	1362 mW
Operating Free-Air Temperature Range	
DS55114	−55°C to +125°C
DS75114	0°C to +70°C
Storage Temperature Range	−65°C to +150°C
Lead Temperature ($1/16$″ from case for 60 seconds): J Package	300°C
Lead Temperature ($1/16$″ from case for 4 seconds): N Package	260°C

*Derate cavity package 9.6 mW/°C above 25°C; derate molded package 10.9 mW/°C above 25°C (Note 2).

Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})			
DS75114	4.75	5.25	V
High Level Output Current (I_{OH})		−40	mA
Low Level Output Current (I_{OL})		40	mA
Operating Free-Air Temperature (T_A)			
DS75114	0	70	°C

Electrical Characteristics Over recommended operating free-air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions (Note 3)			DS75114 Min	DS75114 Typ (Note 4)	DS75114 Max	Units
V_{IH}	High Level Input Voltage				2			V
V_{IL}	Low Level Input Voltage						0.8	
V_{IK}	Input Clamp Voltage	V_{CC} = Min, I_I = −12 mA				−0.9	−1.5	V
V_{OH}	High Level Output Voltage	V_{CC} = Min, V_{IH} = 2V		I_{OH} = −10 mA	2.4	3.4		V
		V_{IL} = 0.8V		I_{OH} = −40 mA	2	3.0		
V_{OL}	Low Level Output Voltage	V_{CC} = Min, V_{IH} = 2V, V_{IL} = 0.8V, I_{OL} = 40 mA				0.2	0.45	V
V_{OK}	Output Clamp Voltage	V_{CC} = 5V, I_O = 40 mA, T_A = 25°C				6.1	6.5	V
		V_{CC} = Max, I_O = −40 mA, T_A = 25°C				−1.1	−1.5	
$I_{O(off)}$	OFF-State Open-Collector Output Current	V_{CC} = Max	V_{OH} = 12V	T_A = 25°				μA
				T_A = 125°C				
			V_{OH} = 5.25V	T_A = 25°C		1	100	
				T_A = 70°C			200	
I_I	Input Current at Maximum Input Voltage	V_{CC} = Max, V_I = 5.5V					1	mA
I_{IH}	High Level Input Current	V_{CC} = Max, V_I = 2.4V					40	μA
I_{IL}	Low Level Input Current	V_{CC} = Max, V_I = 0.4V				−1.1	−1.6	mA
I_{OS}	Short-Circuit Output Current (Note 5)	V_{CC} = Max, V_O = 0V			−40	−90	−120	mA
I_{CC}	Supply Current (Both Drivers)	Inputs Grounded, No Load, T_A = 25°C		V_{CC} = Max		37	50	mA
				V_{CC} = 7V		47	70	

Note 1: All voltage values are with respect to network ground terminal.

Note 2: For operation above 25°C free-air temperature, refer to Dissipation Derating Curves in the Thermal information section.

Note 3: All parameters, with the exception of OFF-state open-collector output current, are measured with the active pull-up connected to the sink output.

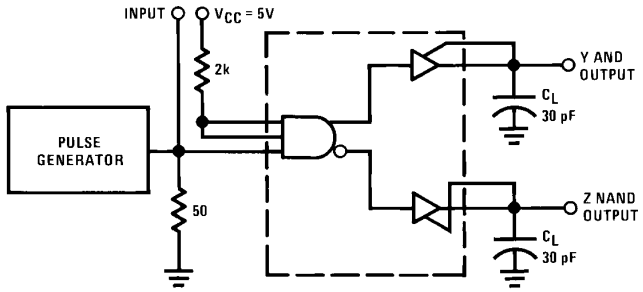
Note 4: All typical values are at T_A = 25°C and V_{CC} = 5V, with the exception of I_{CC} at 7V.

Note 5: Only one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

Switching Characteristics $V_{CC} = 5V, T_A = 25°C$

Symbol	Parameter	Conditions	DS75114			Units
			Min	Typ	Max	
t_{PLH}	Propagation Delay Time, Low-to-High-Level Output	$C_L = 30$ pF, *(Figure 1)*		15	30	ns
t_{PHL}	Propagation Delay Time High-to-Low-Level Output			11	30	ns

AC Test Circuit and Switching Time Waveforms



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Note 1: The pulse generator has the following characteristics: $Z_{OUT} = 50\Omega$, $t_w = 100$ ns, PRR = 500 kHz.

Note 2: C_L includes probe and jig-capacitance.

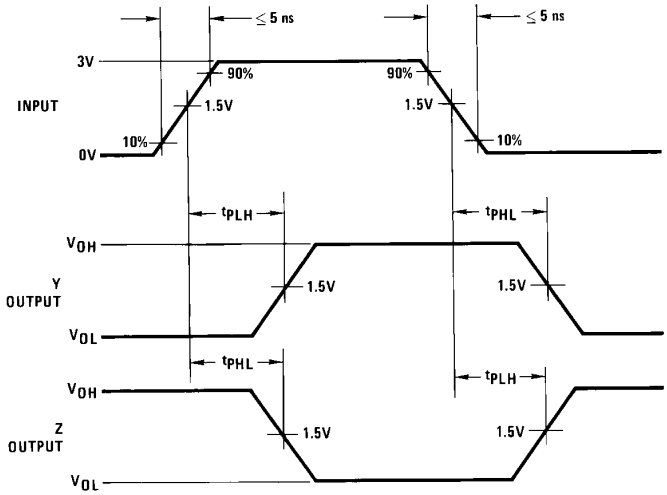

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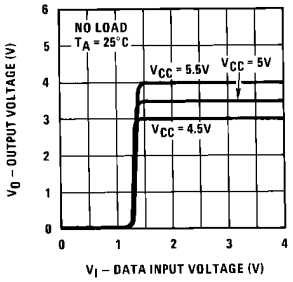
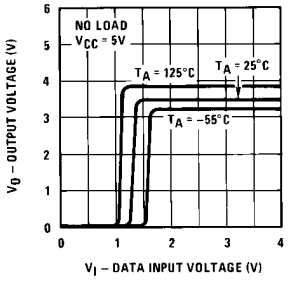
FIGURE 1. (Notes 1, 2)

Typical Performance Characteristics*

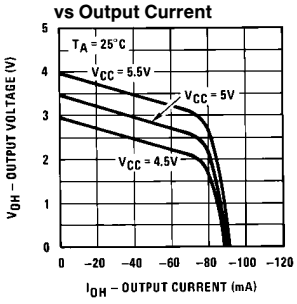
Output Voltage vs Data Input Voltage



Output Voltage vs Data Input Voltage



High Level Output Voltage vs Output Current



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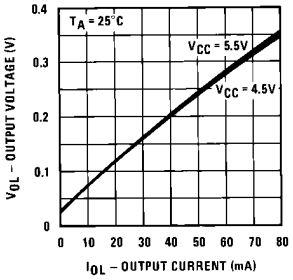
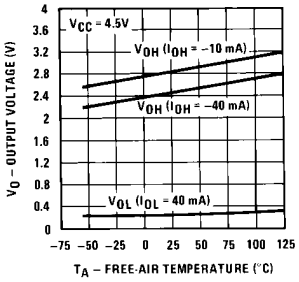
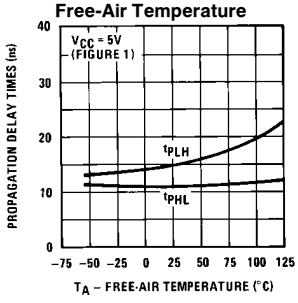
Low Level Output Voltage vs Output Current



Output Voltage vs Free-Air Temperature



Propagation Delay Times vs Free-Air Temperature



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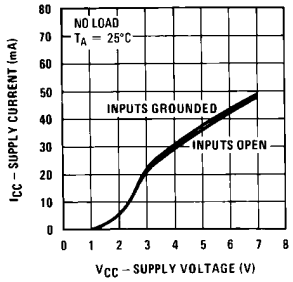
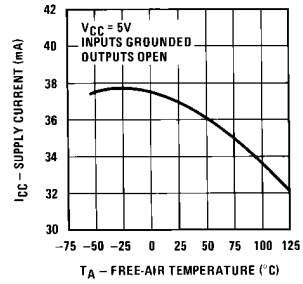
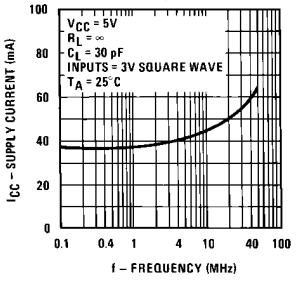
Supply Current (Both Drivers) vs Supply Voltage



Supply Current (Both Drivers) vs Free-Air Temperature



Supply Current (Both Drivers) vs Frequency



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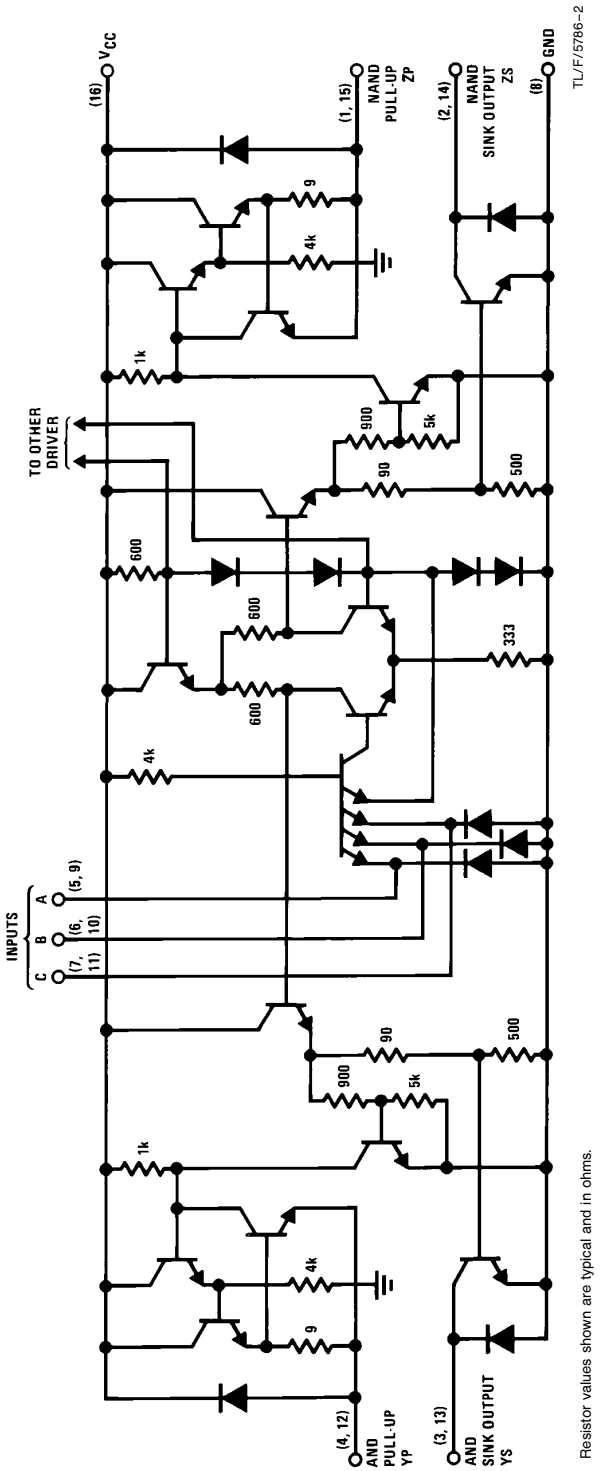
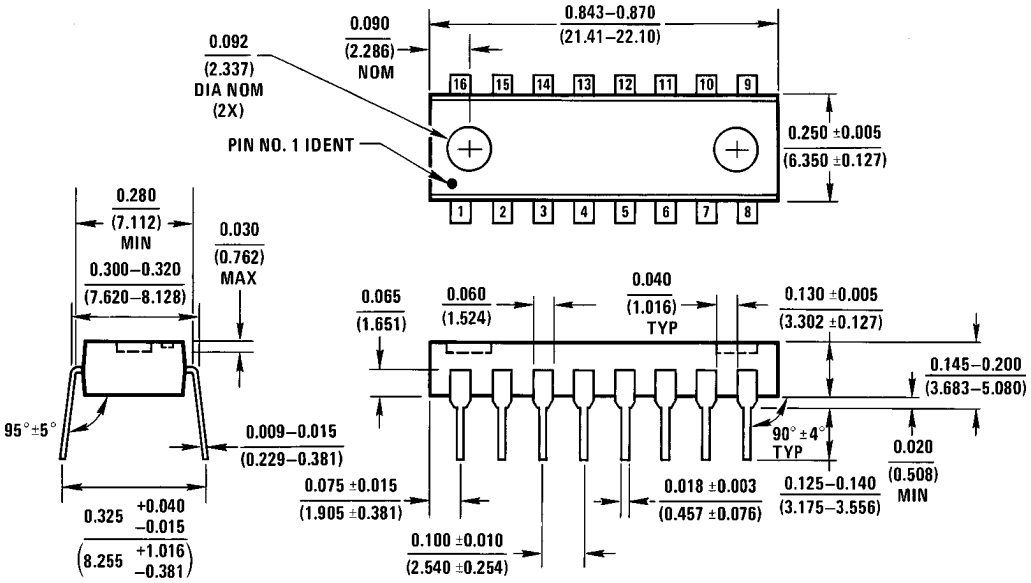
*Data for temperatures below 0°C and above 70°C and for supply voltages below 4.75V and above 5.25V are applicable to DS55114 circuits only. These parameters were measured with the active pull-up connected to the sink output.

Schematic Diagram (Each Driver)



Resistor values shown are typical and in ohms.

Physical Dimensions inches (millimeters)



N16A (REV E)

Molded Dual-In-Line Package (N)
Order Number DS75114N
NS Package Number N16A

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